

a second semiconductor laser element disposed on top of said first semiconductor laser element, said second semiconductor laser element having an emission wavelength different from the emission wavelength of said first semiconductor laser element and a temperature dependence lower than the temperature dependence of said first semiconductor laser element.

7. (*Unamended*) A semiconductor laser device comprising:

a stem having a mounting surface; and  
a plurality of semiconductor laser elements disposed one on top of another and directly or indirectly mounted onto the mounting surface of the stem, said plurality of semiconductor laser elements having different emission wavelengths and different temperature dependencies;

wherein said plurality of semiconductor laser elements are stacked in order of temperature dependence such that the laser chip farther from the mounting surface of the stem has a lower temperature dependence than the laser chip closer to the mounting surface of the stem.

10. (*Unamended*) A semiconductor laser device comprising:

a first semiconductor laser element supported by a mount, said first semiconductor laser element having an emission wavelength and a temperature dependence; and  
a second semiconductor laser element disposed at least partially over said first semiconductor laser element and also supported by the mount, said second semiconductor